# STM simulations as a strucutral tool

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### <u>Outline</u>

- STM theoretical concepts
- Applications



#### Surface Studies by Scanning Tunneling Microscopy

G. Binning, H. Rohrer, Ch. Gerber, and E. Weibel IBM Zurich Research Laboratory, 8803 Rüschlikon-ZH, Switzerland (Received 30 April 1982)

Surface microscopy using vacuum tunneling is demonstrated for the first time. Topographic pictures of surfaces on an *atomic scale* have been obtained. Examples of resolved monoatomic steps and surface reconstructions are shown for (110) surfaces of  $CaIrSn_{\ell}$ and Au.

PACS numbers: 68.20.+t, 73.40.Gk



FIG. 1. Principle of operation of the scanning tunneling microscope. (Schematic: distances and sizes are not to scale.) The piezodrives  $P_x$  and  $P_y$  scan the metal tip M over the surface. The control unit (CU) applies the appropriate voltage  $V_p$  to the piezodrive  $P_z$  for constant tunnel current  $J_T$  at constant tunnel voltage  $V_T$ . For constant work function, the voltages applied to the piezodrives  $P_x$ ,  $P_y$ , and  $P_z$  yield the topography of the surface directly, whereas modulation of the tunnel distance s by  $\Delta s$  gives a measure of the work function as explained in the text. The broken line indicates the z displacement in a y scan at (A) a surface step and (B) a contamination spot, C, with lower work function.



FIG. 3. Two examples of scanning tunneling micrographs of a Au (110) surface, taken at (a) room temperature, and (b) 300 °C after annealing for 20 h at the VOLUME 31, NUMBER 2

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#### Theory of the scanning tunneling microscope

J. Tersoff<sup>\*</sup> and D. R. Hamann AT&T Bell Laboratories, Murray Hill, New Jersey 07974 (Received 25 June 1984)



- Elastic Scattering
- Weak tip-sample interaction:
  - Potential drop localized at vaccuum region
  - First-order approximation for current (Bardeem approximation)
- s-wave model for the tip

#### STM does NOT image atoms, but maps charge density at the tip position & Ef

#### **GOODS**

- Works fine for many systems
- Allows DFT formalisms
- Reproduces bias dependence in semiconductors

#### **BADS**

- No tip features
- Not fully reliable
- Wrong predictions ...
  (atomic resolution?)

#### Tersoff-Hamann theory Application to single Ag



J. Repp et al, Science (04)



#### Tersoff-Hamann theory Application to GaAs(100)-c(8x2)



S.-H. Lee et al, PRL (00)



STM Simulations: green www.icmm.csic.es/jcerda

Geometry

Elastic Scattering

<u>k-sampling</u>

Tunneling regime

EHT approximation

### **Structural Sensitivity**

## Very Variable !!!

• Experiment vs. Theory comparison:

- Image aspect
- Corrugations

• Theoretical variables to play with:

- Surface structure (DFT)
- Tip: nature, structure, orientation, etc.

### GaAs(110) Surface R.M. Feensrta et al, PRL (87)

Empty states Ga atoms



Filled states As atoms

## Rh(111)+nNO (Tip matters)



### Pd(111)+H2O: Low T Water clusters (Corrugation matters)



### Pd(111) + H<sub>2</sub>O (Water 2D quasiperiodic structures)

#### Rosettes

#### Lace



J. Cerdá et al, PRL (04)

## $Ru(0001) + H_2O$

After annealing @200k

Water dosed @150 K After heating @180K Images taken@50K

# Species before Water Desorption (surface oxygen precovered)





#### Experiment



Theory

#### W(110) tip W(111) tip C=0.43 A C=0.29

# Species after Water Desorption (surface oxygen precovered)



#### Si(111)-(-/3x-/3)R30+Y<sub>3</sub>Si<sub>5</sub>+2Si STM depth sensitivity



Vacancies at 3<sup>rd</sup> layer (almost 5 A deep) dictate image aspect despite system is metallic!!

#### Si(111)-(-/3x-/3)R30+Y3Si5 Imaging Buried domain walls







## Pd(111)-p(2x2)+CO+O

#### Experiment Theory











## $Ag(111) + p(4x4)Ag_2O$



#### Experimental



C.I. Carlisle et al, PRL (00)

## Conclusions

- STM simulations is a "mature" field:
  - Most of the experimental features can be well reproduced
- STM simulations can be a very useful tool for structure analysis, but not always !!
  - Different models may yield the same image
- Take care with:
  - Convergence parameters: # atoms/k-points
  - Tip modelling
  - Using normal exp. images for comparison

## Acknowledgements

Theory: M.-L. Bocquet, P. Sautet IRC-CNRS, Villerbaune & ENS de Lyon Pd+H2O: A.Michaelides (Cambridge University, UK) **P. J. Feibelman** (SNL, Alburguegue, USA) T. Mitsui, E. Fomin, M. Rose and M. Salmeron (LBNL, Berkeley, USA) <u>Ru+H<sub>2</sub>O: A. Mugarza, T. Shimizu, D. Ogletree, M. Salmeron</u> (LBNL, Berkeley, USA) Ag<sub>2</sub>O: C.I. Carlisle, M. Webb, A.Alavi & D. King (Cambridge University, UK) CO+O: J. Méndez (ICMM-CSIC) S.H. Kim, J. Wintterlin, G. Ertl (FHI, Berlin) Y3Si5: C. Rogero, J.A. Martín Gago (ICMM-CSIC) **<u>Rh+NO</u>**: K. Flipse, C. Poppa and J. Haagelard (Holland)

# Species before Water Desorption (surface oxygen precovered)



## **Green's Functions**

#### **Definition:** $F(E, K_{par}) = E^*S(K_{par}) - H(K_{par})$ $G(E, k_{par}) * F(E, k_{par}) = I$ Projection onto PLs i,j: $G_{ii} = (F^{-1})_{ii}$ $T_{ii} = G_{ii} (G_{ii})^{-1}$ Sequential Stacking (Dyson): $T_{11} = -G_{11}^{0} F_{11}$ $\Sigma_{II} = F_{II} T_{II}$ $G_{11} = (G_{11}^{0} + \Sigma_{11})^{-1}$ **SGFM** (Moliner): $G_{ii} = G_{ii}^{0} + T_{ii}^{0}(G_{IJ}-G_{IJ}^{0})T_{Ji}^{0}$



## **Bulk Stacking**



-G<sub>b+/-</sub>, T<sub>b+/-</sub>, k<sub>perp</sub>(E), U<sub>kperp</sub>

## Surfaces



#### Surface (Localized) States?

## **Tip-Sample Interaction**



First Order:  $G_{JJ}=G^{0}_{JJ}=>G_{IJ}=T_{IJ}*G^{0}_{JJ}$ 2nd order tunneling events neglected

## **Current Formula**

$$\mathbf{I}(\mathbf{V}) = \Sigma_{kpar} \int d\mathbf{E} \, \sigma(\mathbf{E}, \mathbf{V}, kpar) \, \mathbf{f}_{tip}(\mathbf{E} - \mathbf{eV}) \mathbf{f}_{subs}(\mathbf{E})$$



T<sub>ii</sub>

-Landauer-Büttiker:

Green's Functions (Todorov, Datta):

Subspace of propagative states

## DFT (siesta)

#### - Do self-consistency by pieces





## Some Key Issues

#### -k-sampling

#### -E<sub>i</sub>

Required for integration but induces damping Want to skip surface states?

- $N_E \times N_{PL} \times N_{kc} \times (N_{AO}, N_G)^2$ # atoms > 1000 ;  $N_{AO} \times N_G < 1000 =>$  Fast
- -DM :  $N_E \times N_{PL}^2 \times N_{kc} \times (N_{AO}, N_G)^2$
- Loops: bias , energy , spin , pixels, z<sub>tip</sub> , topography
  save/allocate dynamically

- AO basis small => Corrugations within a factor 2

## **Tip effects**



## Water on Pd(111)

#### Monomer diffusion and clustering



diffusion coefficient • monomer ~ 2.30 x 10<sup>-3</sup> Å<sup>2</sup>/s • dimer > 50 Å<sup>2</sup>/s • trimer, tetramer ~ 1.02 Å<sup>2</sup>/s

T. Mitsui et al, Science (02)





Hexamers forming honeycombs at 40K. Bright molecules at edges: dangling H bonds ?

## Hexamers





W(111) tip Pt(111)

Pt(111) tip